

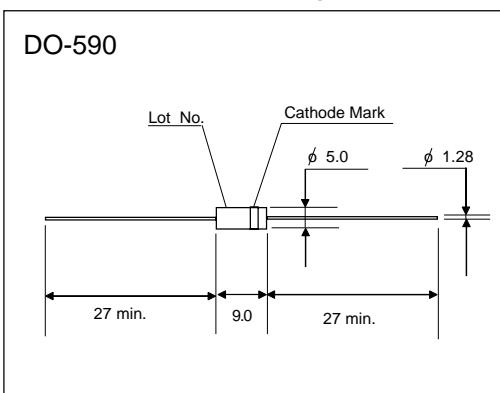
## 2.0kV 2.0A HIGH VOLTAGE DIODES

## ■ Outline Drawings : mm

BR02 is high reliability resin molded type high voltage diode in small size package which is sealed a multilayed mesa type silicon chip by epoxy resin.

## ■ Features

- High speed switching
- High Current
- High surge resistivity for CRT discharge
- High reliability design
- High Voltage



## ■ Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power

## ■ Cathode Mark

Type	Mark
BR02	

## ■ Maximum Ratings and Characteristics

- Absolute Maximum Ratings

Items	Symbols	Condition	BR02	Units
Repetitive Peak Reverse Voltage	$V_{RRM}$		2.0	kV
Average Output Current	$I_o$	$T_a=25^\circ C$ , Resistive Load	2.0	A <sub>peak</sub>
Surge Current	$I_{FSM}$		40	A <sub>peak</sub>
Junction Temperature	$T_j$		125	°C
Allowable Operation Case Temperature	$T_c$		125	°C
Storage Temperature	$T_{stg}$		-40 to +125	°C

- Electrical Characteristics ( $T_a=25^\circ C$  Unless otherwise specified )

Items	Symbols	Conditions	BR02	Units
Maximum Forward Voltage Drop	$V_F$	at $25^\circ C$ , $I_F = I_{F(AV)}$	2.4	V
Maximum Reverse Current	$I_{R1}$	at $25^\circ C$ , $V_R = V_{RRM}$	3.0	uA
	$I_{R2}$	at $100^\circ C$ , $V_R = V_{RRM}$	30	uA
Maximum Reverse Recovery Time	$T_{rr}$	at $25^\circ C$	--	nS
Junction Capacitance	$C_j$	at $25^\circ C$ , $V_R=0V$ , $f=1MHz$	--	pF